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Modulating magnetic anisotropy in Ln(III) single-ion magnets using an external electric field†

Arup Sarkar  and Gopalan Rajaraman *

Single-molecule magnets have potential uses in several nanotechnology applications, including high-density information storage devices, the realisation of which lies in enhancing the barrier height for magnetisation reversal (U_{eff}). However, Ln(III) single-ion magnets (SIMs) that have been reported recently reveal that the maximum value of U_{eff} values that can be obtained by modulating the ligand fields has already been achieved. Here, we have explored, using a combination of DFT and *ab initio* CASSCF calculations, a unique way to enhance the magnetisation reversal barrier using an oriented external electric field in three well-known Ln(III) single-ion magnets: [Dy(Py)₅(O^tBu)₂]⁺ (**1**), [Er{N(SiMe₃)₂Cl}]⁻ (**2**) and [Dy(Cp^{Me3})Cl] (**3**). Our study reveals that, for apt molecules, if the appropriate direction and values of the electric fields are chosen, the barrier height can be enhanced by twice that of the limit set by the ligand field. The application of an electric field along the equatorial direction was found to be suitable for oblate shaped Dy(III) complexes and an electric field along the axial direction was found to enhance the barrier height for a prolate Er(III) complex. For complexes **2** and **3**, the external electric field was able to magnify the barrier height to 2–3 times that of the original complexes. However, a moderate enhancement was noticed after application of the external electric field in the case of complex **1**. This novel non-chemical fine-tuning approach to modulate magnetic anisotropy is expected to yield a new generation of SIMs.

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Introduction

There is great interest in the area of single-molecule magnets (SMMs), as they are reported to have potential applications in information storage devices, cryogenic refrigeration, quantum computing and spintronic devices *etc.*¹ SMMs containing lanthanide(III) ions have gained interest in recent years, as they possess a huge barrier height for magnetisation reversal (U_{eff}) and, at the same time, possess record high blocking temperatures (T_{B}). While there are various classes of molecules that exhibit blocking temperatures in the range of 4–15 K,² higher blocking temperatures can be found for organometallic Dy(III) single-ion magnets (SIMs) containing substituted cyclopentadienyl ligands (T_{B} in the range of 48 K to 80 K).³ It is well-known that the shape of the electron density of the ground state m_{J} levels of the lanthanide ion is critical in dictating the magnetic properties. The Ln(III) ions can be classified as follows: (i) those possessing oblate density require strong axial ligands with no/weak equatorial ligation, and (ii) those with prolate density demand strong equatorial ligands with weak/no axial ligation. Synthetic chemists have utilised these ideas to develop

novel molecules with attractive U_{eff} and T_{B} values.⁴ While most of the molecules that possess very high-blocking temperatures also possess substantial U_{eff} values, often the T_{B} value is only a fraction of the reported U_{eff} value. While establishing the relationship between the U_{eff} and T_{B} values and the mechanism beyond the single-ion relaxation has gained attention,⁵ it is also equally important to realise large U_{eff} values in order to move forward.

Various chemical fine-tuning methods, such as (i) using designer ligands that control the ligand field around the Ln(III) ion in an anticipated fashion,⁶ (ii) maintaining the symmetry around the metal centre,^{2,7} (iii) incorporating diamagnetic elements in the cluster aggregation to enhance the axiality⁸ or (iv) incorporating a transition metal or radicals to induce an exchange interaction as a way to suppress tunnelling, have been explored to obtain larger U_{eff} values.^{4a,9} With numerous Dy(III) mononuclear complexes reported in the literature, it has been stated that the axial limit that controls the overall U_{eff} value has been reached.^{2a} While increasing the T_{B} value has been the focus for the present, other avenues to enhance the U_{eff} values have not been explored. As chemical fine-tuning of the ligand field has already reached its potential, we aim to search for an alternative route to enhance the U_{eff} values in Ln(III) SIMs. In this context, using various computational tools, here we set out to explore the role of an applied electric field in the magnetisation reversal of Ln(III) SIMs. Recent examples in this area

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where an electric field has been utilised to modulate the magnetic properties offered strong motivation for this work.¹⁰ To enumerate the effect of an oriented external electric field (OEEF) on lanthanide SIMs, we chose three example complexes, [Dy(Py)₅(O^tBu)₂][BPh₄]^{2a} (**1**), Li(THF)₄[Er{N(SiMe₃)₂}₃Cl]¹¹ (**2**), and [Dy(Cp^{Me3})₂Cl]^{3c} (**3**). All three complexes were characterized well and are among the best-known SIMs in their family. In particular, complex **1** was found to exhibit an U_{eff} value of 1815 K with a blocking temperature of 14 K, while complex **2** was found to have an U_{eff} value of 63 K with a T_{B} of 3 K. Complex **3**, on the other hand, did not exhibit any out-of-phase signals and, therefore, is not a single-ion magnet.^{3c}

Results and discussion

Computing the magnetic anisotropy of Ln(III) SIMs in the presence of an electric field has not been attempted before, and multiple challenges are present to account for such effects. The application of oriented electric fields is expected to distort the geometry, and capturing this effect is crucial in understanding the magnetic anisotropy. As Ln(III) SIMs are known to be extremely sensitive to small structural changes, static OEEFs on an X-ray structure are unlikely to reveal the real scenario. As structure optimisation with *ab initio* CASSCF calculations is not practical at the present time, here, we have chosen a combination of methodologies, wherein DFT calculations in the presence of an electric field were utilized to obtain reasonable structures.

These structures were then subject to *ab initio* CASSCF/RASSI-SO/SINGLE_ANISO calculations in the presence of the same electric field, in order to capture both the structural distortion and also the electric field effect on the magnetic anisotropy (see computational details for more information). *Ab initio* calculations were performed on the crystal structures of the complexes (or models derived from the X-ray structures) of **1-3** in the absence of any external perturbation (see Tables S1–S3 in the ESI[†]). Complexes **1** and **2** are well-known examples, and exhibited strong axiality in the estimated g_z values with computed barrier heights of 1183 cm⁻¹ and 181 cm⁻¹, respectively (relaxation *via* 4th excited Kramers doublet).^{2a,12}

As the geometries of **1** and **2** are relaxed in the presence of an electric field, it is imperative to understand how the optimised geometry in the gas phase correlates to the X-ray structure. The optimised geometries of the complexes (**1_{opt}** and **2_{opt}**) reveal elongation of all the bonds within the molecules, as intermolecular interactions in the crystal lattices are removed. The axial Dy–O(1) bond length increases from 2.110 Å in the X-ray structure to 2.142 Å in **1_{opt}**, and the average equatorial Dy–N bond length also increases by ~0.05 Å in the geometry of **1_{opt}** (see Table 1). A similar elongation was seen in the Er–N/Cl bond lengths in complex **2**. The CASSCF calculations of **1_{opt}** and **2_{opt}** yield U_{cal} values of 1118 cm⁻¹ and 144 cm⁻¹, respectively, assuming relaxation *via* the 4th excited state (see Fig. 1). These computed values are slightly smaller than the values obtained from the X-ray structures, and this is due to relatively weaker axial ligand fields (LFs) in the optimised geometries (see Tables S4 and S5[†]).

Table 1 Selected structural parameters of complexes **1** and **2** in the presence of an electric field. Bond lengths and τ in Å, angles are in (°) and the U_{cal} values are in cm⁻¹

	X-ray	1_{opt}	^{4z} 1_{opt}	^{8z} 1_{opt}	^{12z} 1_{opt}	^{4x} 1_{opt}	^{8x} 1_{opt}	^{12x} 1_{opt}
Dy–O1	2.114	2.141	2.170	2.203	2.244	2.138	2.138	2.139
Dy–O2	2.110	2.142	2.118	2.098	2.081	2.140	2.139	2.139
Dy–N1	2.534	2.616	2.604	2.605	2.604	2.649	2.710	2.798
Dy–N2	2.556	2.610	2.616	2.616	2.619	2.604	2.574	2.554
Dy–N3	2.563	2.618	2.626	2.625	2.628	2.604	2.582	2.559
Dy–N4	2.572	2.618	2.606	2.608	2.607	2.615	2.642	2.674
Dy–N5	2.580	2.612	2.629	2.627	2.626	2.617	2.630	2.649
∠O1–Dy–O2	178.9	178.3	178.5	178.3	178.0	171.2	164.6	157.2
U_{cal}	1183	1118	1108	1083	1040	1111	1070	939

	X-ray	2_{opt}	^{4z} 2_{opt}	^{8z} 2_{opt}	^{12z} 2_{opt}	^{16z} 2_{opt}	^{20z} 2_{opt}	^{26z} 2_{opt}
Er–Cl	2.528	2.586	2.614	2.647	2.686	2.736	2.803	3.042
Er–N1	2.231	2.308	2.304	2.301	2.298	2.295	2.293	2.285
Er–N2	2.251	2.308	2.304	2.301	2.298	2.295	2.292	2.284
Er–N3	2.246	2.309	2.306	2.303	2.302	2.300	2.300	2.296
τ	0.454	0.508	0.488	0.468	0.446	0.419	0.385	0.293
U_{cal}	181	144	163	178	200	223	250	317

In the next step, we attempted to optimise the geometry in the presence of an oriented external electric field (OEEF) starting from 0.004 au (atomic unit, equivalent to 0.2 V Å⁻¹).^{10c,13} The electric field applied here varied from 0.004 au to 0.026 au and lies within the limits of ionisation energies and bond dissociation energies, and is accessible for most of the STM tips.^{13,14} While the electric field-induced spectroscopic techniques use a smaller field, organic reactions that are performed using an OEEF are comparable to the electric field utilised here.^{13,14} Applying the electric field along the +z-axis (which is co-linear with the g_z axis for complex **1**) in **1_{opt}** (see Fig. 1a, b and S1 in the ESI[†]) elongates the Dy–O(1) bond and, at the same time, shortens the Dy–O(2) bond, and therefore breaks the pseudo- D_{5h} symmetry of the molecule. We performed *ab initio* CASSCF calculations on this optimised geometry for ^{4z}**1_{opt}** (here, the superscript denotes the amount of OEEF applied $\times 10^{-3}$ au along the +z direction) in the presence of an electric field (EF), wherein a reduction in the barrier height was witnessed. This is due to the fact that Dy–O(1) bond elongation causes weakening of the axial LF and hence reduces the axial anisotropy for the oblate Dy(III) ion. Although a simultaneous shortening of the Dy–O(2) bond is seen, the ^{4z}**1_{opt}** geometry reveals that elongation is larger than the shortening (see Fig. S1[†]). This asymmetric distortion leads to a smaller U_{cal} value of 1108 cm⁻¹ for ^{4z}**1_{opt}**. In the next step, we increased the OEEF value in a step-wise manner to 0.012 au, and could clearly see that an increase in the electric field increases the Dy–O(1) bond further and, at the same time, shortens the Dy–O(2) bond, albeit asymmetrically. This led to a further reduction in the barrier height, with a value of 1040 cm⁻¹ noted for the ^{12z}**1_{opt}** structure (see Tables S6 and S9–S11 in the ESI[†]). This reduction in the barrier height can be rationalised by analysing the LoProp charges at the spin-free ground state. By increasing OEEF, the LoProp charge on O(1) gradually decreases, while it is increased on O(2) (see



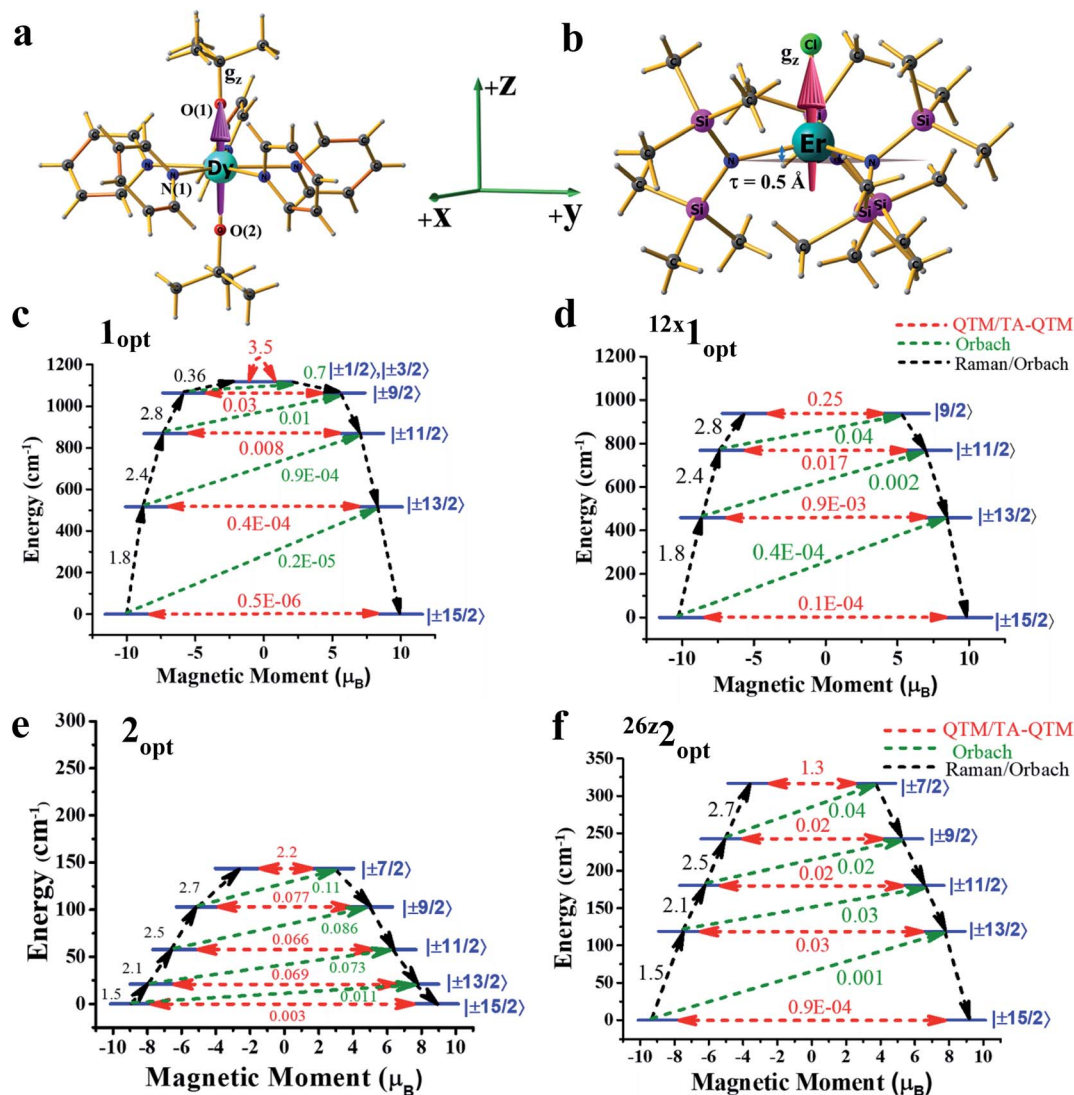


Fig. 1 Optimised geometries and *ab initio* blocking barriers at different external electric fields: structures of (a) 1_{opt} and (b) 2_{opt} , along with the computed g_z -axis. Colour code: Dy – cyan, Er – dark cyan, N – blue, Cl – green, Si – pink, C – grey, and H – light grey. *Ab initio* blocking barriers and relaxation mechanisms of complexes (c) 1_{opt} , (d) $12x1_{\text{opt}}$, (e) 2_{opt} and (f) $26z2_{\text{opt}}$. For figures c–f, the red arrows indicate the QTM or TA-QTM via ground or excited KDs, respectively. The blue characters indicate the major components of m_J of a KD. The green dotted arrows show the mechanisms of the Orbach processes. The black arrows indicate the pathways of magnetic relaxation.

Tables S8 and S16†). Perceiving this effect, we switched the OEEF along the x/y direction for complex 1_{opt} (see Fig. S1 in the ESI†), and this yields structure of $4x1_{\text{opt}}$ (here, the superscript denotes the amount of OEEF applied $\times 10^{-3}$ au along the $+x$ direction). Here, the Dy–N(1) bond length was found to increase sharply from 2.62 Å to 2.80 Å, *vis-à-vis*, the geometries of 1_{opt} vs. $12x1_{\text{opt}}$ (see Table 1) and, at the same time, two of the Dy–N bonds (along the $-x$ -direction) were found to shorten asymmetrically. Also, the effect of applying an OEEF along the Dy–N(1) direction could be seen by a substantial decrease in the LoProp charge of the N(1) atom, while the charges on the oxygen atoms remained unaltered (see Table S8 in the ESI†). As three Dy–N bonds were significantly elongated in the geometry of the $12x1_{\text{opt}}$ complex, it could be expected to possess a large barrier height. However, *ab initio* calculations revealed the contrary,

with the barrier height diminishing with an increase in OEEF value, yielding a U_{cal} value of 939 cm^{-1} for $12x1_{\text{opt}}$, and this relaxes *via* 3rd excited KDs (see Tables S7 and S12–S14 in the ESI†). This is due to the fact that an alteration of the Dy–N distances is accompanied by a variation in the $\angle\text{O–Dy–O}$ angle, which is reduced to 157° in $12x1_{\text{opt}}$ from 178° in the geometry of 1_{opt} (see Table 1). Thus, the application of the electric field along the perpendicular or g_x -direction decreases the barrier height in complex 1. In addition, in both directions (x or z), the ground state as well as the excited state, the QTM (quantum tunnelling of magnetisation) values increase for complex 1, further supporting the reduction in the U_{cal} values. To prove that the reduction is solely due to the $\angle\text{O–Dy–O}$ angle bending, we performed one additional set of calculations on the geometry of $12x1_{\text{opt}}$, where the $\angle\text{O–Dy–O}$ angle was fictitiously set at





Fig. 2 Arrangement of the application of an external electric field. (a) Result of applying an OEEF on a polar Ln–L bond axis. (b) Arrangement of applying an external electric field by placing point charges on two opposite Pt (111) layers that are 35 Å apart, and the molecule is at the centre, during *ab initio* calculations (the distance between the molecule to the Pt layers is not to scale). For more information see the computational details.

178° and this structure yielded a barrier height of 1162 cm^{-1} (see Fig. S2 and Table S15 in the ESI†). This estimated value is $\sim 50 \text{ cm}^{-1}$ higher, compared to the optimised geometry, offering a possibility, however small, of enhancing the U_{cal} value in **1** using an applied electric field. Furthermore, increasing the OEEF to 0.016 au resulted in dissociation of the Dy–N bond, and this sets the electric field limit in the x/y direction of the molecule.

To further understand how the alteration of the structure occurs due to the applied OEEF, it is important to understand the nature of dipoles and their behaviour in the applied electric field conditions. The application of an OEEF is expected to polarise a non-polar bond and enhance the ionic character of a polar bond.¹³ For a Ln–L bond, the application of an OEEF will stretch it further if the dipolar field creates an opposite dipole with respect to the Ln–L dipole, and will shorten it if the dipolar field is in the same direction as the Ln–L dipole (see Fig. 2a). Therefore, the molecule has to be chosen in such a way that an increase in the Ln–L bond length will enhance the magnetic anisotropy and will subsequently increase the barrier height (U_{eff}).

Applying an OEEF along an equatorial Ln–L bond in oblate ions, such as Dy(III), or along an axial Ln–L bond in prolate ions, such as Er(III), is thus likely to increase the U_{eff} value beyond the reported values from the X-ray structures. However, if the OEEF is applied along the opposite directions, it is expected to further decrease the U_{eff} values.

Based on the knowledge gained, we intuitively expanded the study to a prolate Er(III) ion using complex **2**. We narrowed it down to this example for two reasons: (i) to choose a well-studied prolate Er(III) SIM with a significant barrier height, and (ii) to choose an Er(III) SIM with a strong equatorial ligand

and a weak axial ligand along only one direction, as this would be expected to facilitate the enhancement of the U_{cal} value upon application of an OEEF. Upon application of the OEEF along the Er–Cl direction (g_z axis, see Fig. 2b), with the same step-size as before, the Er–Cl bond length was found to increase significantly (see Fig. S3 in the ESI† and Table 1), reaching a value of 2.91 Å at 0.024 au E_z ($^{24z}2_{\text{opt}}$). To determine the tolerance limit, we further increased the electric field to 0.026 au E_z ($^{26z}2_{\text{opt}}$) and found that the Er–Cl bond length elongated further to 3.04 Å. The application of an OEEF beyond this value was found to cleave the Er–Cl bond, suggesting a possible ionisation/decomposition limit.

Additionally, the $\{N_3Er\}$ out-of-plane pyramidal shift (parameter τ , see Fig. 2 and S3 in the ESI†) was also found to change upon application of the OEEF. As the OEEF was applied along the Er–Cl bond, this bond elongates and pushes the Er(III) ion down, and therefore decreases the τ value. The τ value decreased from 0.5 Å in the 2_{opt} complex to 0.3 Å at $^{26z}2_{\text{opt}}$. If the OEEF was applied along the $-z$ -direction (Cl–Er direction), this tended to enhance the pyramidalisation (see Fig. S3 in the ESI†) and, thus, the τ value increased to 0.62 Å at $^{26-z}2_{\text{opt}}$. Theoretical studies performed earlier on complex **2** revealed that this is an important parameter that enhances the barrier height.¹⁵

The application of an OEEF along the g_z axis in **2** (*i.e.* along the Er–Cl bond) enhanced the value of U_{cal} from 163 cm^{-1} at $^{4z}2_{\text{opt}}$ to a remarkable 317 cm^{-1} at $^{26z}2_{\text{opt}}$. This estimate is one of the highest obtained for any Er(III) SIMs.¹⁶ Computed QTM (and TA-QTM) values revealed a smooth decrease of these values from 2.2 μ_B at $^{4z}2_{\text{opt}}$ to 1.3 μ_B at $^{26z}2_{\text{opt}}$ (see Tables S17–S24 in the ESI†). In addition, a smooth linear increase of the negative B_2^0 parameter was observed for complex **2** under the applied electric field range along the $+z$ direction (see Fig. S4 and Table S27 in the ESI†). If an OEEF was applied in the reverse direction on complex **2**, *i.e.* along the $-z$ -direction, a reverse trend was visible, with a gradual decrease in the U_{cal} value. As expected, here the Er(III)–Cl bond length decreased and a decrease in the τ value was noticed upon application of an electric field in the $-z$ -direction. The U_{cal} value decreased from 131 cm^{-1} for $^{4-z}2_{\text{opt}}$ to the much smaller value of 52 cm^{-1} (*via* the 3rd excited state) for the $^{24-z}2_{\text{opt}}$ structure (see Tables S25–S27 in the ESI†). Furthermore, the U_{cal} value diminishes to zero for $^{26-z}2_{\text{opt}}$, with a notable ground state QTM. We also plotted the β -electron density of Er(III) under the applied electric field conditions, and this reflects well with the observed changes (see Fig. S5† for a plot corresponding to $^{26-z}2_{\text{opt}}$, 2_{opt} and $^{26z}2_{\text{opt}}$).

After achieving such a large U_{cal} value for complex **2**, we extended the study further to another Dy(III) example, namely $[\text{Dy}(\text{Cp}^{\text{Me}_3})_2\text{Cl}]$ (complex **3**) (Cp^{Me_3} = trimethylcyclopentadienyl) (see Fig. 3a), which is a model complex derived from the X-ray structure of the famous precursor, $[\text{Dy}(\text{Cp}^{\text{tH}})_2\text{Cl}]$.^{3a} The calculations on the optimised structure (3_{opt}) revealed a very small U_{cal} value of 144 cm^{-1} relaxing *via* the first excited state due to high QTM being in operation due to the coordination of $-\text{Cl}$ along the equatorial direction (see Tables S28 and S29 in the ESI†). In order to quench this QTM, we applied the OEEF along the Dy–Cl bond direction (perpendicular to the g_z axis), and this led to the weakening of the Dy–Cl bond and a gradual increase in the U_{cal}





Fig. 3 Details of the application of an external electric field in complex 3. (a) DFT optimised geometry of complex 3, along with the g_{zz} axis and the three cartesian axes directions. (b) An *ab initio* computed magnetization blocking barrier diagram of $^{22z}3_{\text{opt}}$. See Fig. 1 caption for further details. (c) Variations in the Dy–Cl bond length and (d) Cp–Dy–Cp angle with respect to the oriented external electric field.

value from 160 cm^{-1} at $^{4z}3_{\text{opt}}$ (here the +z direction indicates application of OEEF along the Dy–Cl bond axis) to 519 cm^{-1} in the $^{22z}3_{\text{opt}}$ structure (see Table S29[†] and Fig. 3a–d). The Dy–Cl bond length increased from 2.59 \AA for $^{4z}3_{\text{opt}}$ to 2.94 \AA for $^{22z}3_{\text{opt}}$. As the Dy–Cl bond distance increases with the applied electric field, two other important structural parameters were also found to have been altered. Firstly, the distance between the two Cp rings was found to decrease and, secondly, the Cp–Dy–Cp angle was found to increase (see Table S28 in the ESI[†]). The application of an electric field beyond 0.022 au resulted in the rupture of the Dy–Cl bond. At the $^{22z}3_{\text{opt}}$ geometry, the U_{cal} value estimated is found to be three times larger than the optimized structure obtained in the absence of OEEF (3_{opt}).

While the QTM (or TA-QTM) probabilities have been found to alter upon the application of an electric field, the challenge of controlling the blocking temperature still remains. As the electric field modifies the geometry, this in turn alters the corresponding molecular vibrations and hence offers a way to control the molecular vibrations that are responsible for magnetisation relaxation. This idea can be utilised to modulate the prominent vibrations that are responsible for the reduction in the blocking temperature, and work in this direction is currently underway in our laboratory.

Conclusions

As chemical fine-tuning of the ligand field has already reached its potential, here we set out to search for an alternative route to enhance the U_{eff} values in Ln(III) SIMs. In this context, we explored the role of an applied external electric field in the magnetisation reversal in $[\text{Dy}(\text{Py})_5(\text{O}^t\text{Bu})_2]^+$ (1), $[\text{Er}\{\text{N}(\text{SiMe}_3)_2\}_3\text{Cl}]^-$ (2), and $[\text{Dy}(\text{Cp}^{\text{Me}_3})_2\text{Cl}]$ (3) single-ion magnets. Our calculations revealed a moderate improvement in the U_{cal} value of 1 if the electric field was applied along the g_x direction. Learning from this example, we studied the $[\text{Dy}(\text{Cp}^{\text{Me}_3})_2\text{Cl}]$ complex, where the application of an electric field along the Dy–Cl direction was found to weaken the Dy–Cl bond, leading to an enhancement of the barrier height by three times (it was increased from 144 cm^{-1} at a 0.004 au electric field to a remarkable 519 cm^{-1} at a 0.022 au electric field), compared to the original molecule. Based on these understandings, we intuitively studied $[\text{Er}\{\text{N}(\text{SiMe}_3)_2\}_3\text{Cl}]^-$, where the application of an electric field along the Er–Cl g_z -direction was found to boost the barrier height twice that of the reported U_{eff} values. The enhancement in the U_{cal} value was much larger than that of the X-ray structures, offering a viable non-chemical method to enhance the barrier height beyond the limits set by the ligand



fields. This novel approach is expected to generate substantial interest in obtaining new generation SIMs, unveiling its potential applications.

Computational details

DFT calculations

All the geometry optimisations were performed with DFT (Density Functional Theory) calculations using the Gaussian 09 package (revision D.01).¹⁷ During geometry optimisations, we replaced the central Dy(III) and Er(III) ions with a diamagnetic Y(III) ion, as this ion has a similar ionic radius. The hybrid B3LYP functional, along with the SDD basis set¹⁸ and corresponding ECP basis set for Y and the Ahlrichs split-valence polarisation (SVP)¹⁹ for the rest of the atoms were used during the optimisation steps. In addition, the diffused 6-31+G(d,p) basis set was tested and used for the non-metals and compared with the SVP results. The geometrical parameters were found not to change upon changing the basis set from SVP to 6-31+G(d,p). An oriented external electric field (OEEF) was applied during the optimisation in a particular direction using the Field keyword available in G09 suite. The OEEF was increased with a step-size of a 0.004 au electric field, which is equivalent to 0.2 V Å⁻¹ (1 au = 51.4 V Å⁻¹).

Ab initio calculations

After the geometry optimisation at different electric fields, the optimised complexes were inserted between the Platinum (Pt) layers for single point CASSCF calculations. Here, in the *ab initio* setup, the central metal ion was placed back into the original lanthanide centres to perform anisotropy calculations in the presence of the external electric field. Since the OEEF was applied along a particular direction during the DFT calculations, a similar orientation was fixed during the *ab initio* setup as well. All the *ab initio* single point calculations were performed using the MOLCAS 8.0 program package.²⁰ Here, a multi-configurational CASSCF (complete active space self-consistent field) method was chosen to compute the spin-Hamiltonian parameters. We employed relativistic contracted atomic natural orbital type basis sets: [ANO-RCC-VTZP...8s7p5d3f2g1h] for Ln(III) {Ln = Dy, Er}, ANO-RCC-VDZP (ANO-RCC...6s5p3d1f) for Si and Cl, ANO-RCC-VDZP (ANO-RCC...3s2p1d) for N and O, ANO-RCC-VDZ (ANO-RCC...3s2p) and ANO-RCC-VDZP (in the case of complex 3) for C, and ANO-RCC-VDZ (ANO-RCC...2s) for H, throughout our calculations. First, we performed a simple low-level SCF to generate the starting estimated orbitals in the Guessorb step. The Pt(111) layer was introduced as point charges to generate the external static electric field using the XFIELD keyword available in MOLCAS suite. In order to generate the external electric field for the *ab initio* calculations in MOLCAS, we placed two oppositely charged single Pt(111) layers, each containing 39 Pt atoms of dimension 14 × 14 (Å),² on each side and at 35 Å apart (see Fig. 2b in the main manuscript). Point charges of the different signs were imposed on the opposite Pt(111) layers to generate the electric field, mimicking the electrode setup. Then, in this arrangement, the optimised Dy^{III}/Er^{III} complex was placed exactly at the centre of the two

Pt(111) layers. It was assumed that no chemical interaction was possible between the two layers and the molecule, as the distance is too high (~15 Å). More precisely, the electric field was directed perpendicular to the Pt layers. The direction of the electric field could be switched by altering the sign of the charges on the Pt(111) layers. The charges were chosen in a trial and error method, so that the generated electric field matched exactly with the oriented electric field used earlier during optimisation in DFT. The imposed point charges and the corresponding generated electric fields at the origin or centre of the Pt layer were calculated and are listed in Tables S6 and S7.†

The AMFI (atomic mean field integral) spin-orbit operator was introduced to account for the spin-orbit effects. The scalar relativistic effect was considered using the DKH Hamiltonian. The Cholesky decomposition method was adopted to accelerate the two-electron integral calculation. In the configuration interaction (CI) step (CASSCF), an active space of 9 electrons in seven 4f orbitals, *i.e.* CAS(9,7) for Dy; 11 electrons in seven 4f orbitals, *i.e.* CAS(11,7) for Er(III) were considered throughout the calculations. This active space was optimised with 21 sextets for Dy(III), and 35 quartets and 112 doublets for Er(III). The spin-orbit coupling was taken into account using the RASSI-SO (Restricted Active Space State Interaction Spin-Orbit) module, which acts on all the spin-free states generated from the CASSCF wavefunctions. Finally, eight lower energy ground state Kramer doublets (KDs) for Dy(III) and Er(III) were used for the calculation of the spin-Hamiltonian properties, such as the *g* tensor values, using a specially designed routine SINGLE-ANISO module.

Crystal field description

The crystal field Hamiltonian for lanthanide coordination complexes has been defined as follows,

$$\hat{H}_{\text{CF}} = \sum_{k=-q}^q B_k^q \tilde{O}_k^q$$

where B_k^q and O_k^q are the extended crystal field (CF) operator and the Stevens operator, respectively. Here, if the value of k is 2, then B_k^q is the tensor quantity, and $k = 2$ (higher-order indices like 4, 6, ... are also possible), where $q = 0$ denotes an axial crystal field and a non-zero value of q denotes a non-axial crystal field.²¹ Therefore, a large negative $B_{k=2,4,\dots}^{q=0}$ value with a very small $B_{k=2,4,\dots}^{q \neq 0}$ value indicates axial anisotropy and the reverse situation indicates transverse magnetic anisotropy.

Conflicts of interest

There are no conflicts to declare.

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